

N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

The μ PA1852 is a switching device which can be driven directly by a 2.5-V power source.

The μ PA1852 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- Can be driven by a 2.5-V power source
- Low on-state resistance $R_{DS(on)1} = 40 \text{ m}\Omega \text{ MAX.}$ (Vgs = 4.5 V, Ip = 3.0 A) $R_{DS(on)2} = 45 \text{ m}\Omega \text{ MAX.}$ (Vgs = 4.0 V, Ip = 3.0 A) $R_{DS(on)3} = 60 \text{ m}\Omega \text{ MAX.}$ (Vgs = 2.5 V, Ip = 3.0 A)
- Built-in G-S protection diode against ESD

ORDERING INFORMATION

PART NUMBER	PACKAGE		
μPA1852GR-9JG	Power TSSOP8		

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Drain to Source Voltage	VDSS	20	
Gate to Source Voltage	Vgss	±12	
Drain Current (DC)	ID(DC)	±6.0	
Drain Current (pulse) Note1	D(pulse)	±24	
Total Power Dissipation Note2	Рт	2.0	
Channel Temperature	Tch	150	
Storage Temperature	Tstg	–55 to +150	

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1 %

2. Mounted on ceramic substrate of 5000 mm² x 1.1 mm

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

V

V

A

Α

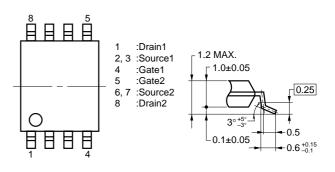
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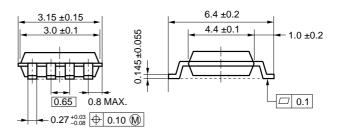
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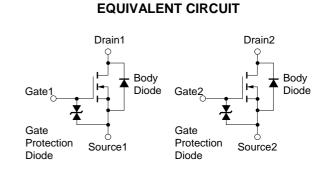
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PACKAGE DRAWING (Unit : mm)



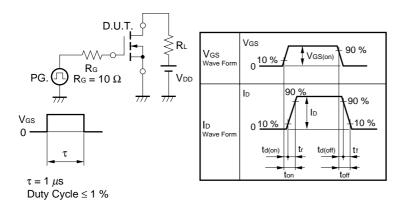




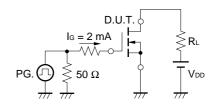
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Cut-off Current	IDSS	Vds = 20 V, Vgs = 0 V			10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 12 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Gate Cut-off Voltage	VGS(off)	V _{DS} = 10 V, I _D = 1 mA	0.5	0.74	1.5	V
Forward Transfer Admittance	y _{fs}	Vds = 10 V, Id = 3.0 A	1	10		S
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = 4.5 V, I_{D} = 3.0 A$		29	40	mΩ
	RDS(on)2	$V_{GS} = 4.0 V, I_{D} = 3.0 A$		31	45	mΩ
	RDS(on)3	Vgs = 2.5 V, Id = 3.0 A		39	60	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		420		pF
Output Capacitance	Coss	Vgs = 0 V		265		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		120		pF
Turn-on Delay Time	td(on)	Vdd = 10 V		55		ns
Rise Time	tr	ID = 1.5 A		160		ns
Turn-off Delay Time	td(off)	$V_{GS(on)} = 4.0 V$		385		ns
Fall Time	tr	Rg = 10 Ω		355		ns
Total Gate Charge	QG	Vdd = 10 V		6		nC
Gate to Source Charge	QGS	ID = 6.0 A		2		nC
Gate to Drain Charge	Qgd	Vgs = 4.0 V		3		nC
Diode Forward Voltage	VF(S-D)	IF = 6.0 A, VGS = 0 V		0.74		V
Reverse Recovery Time	trr	IF = 6.0 A, VGS = 0 V		20		ns
Reverse Recovery Charge	Qrr	di/dt = 15 A/ μ s		2		nC

TEST CIRCUIT 1 SWITCHING TIME



TEST CIRCUIT 2 GATE CHARGE

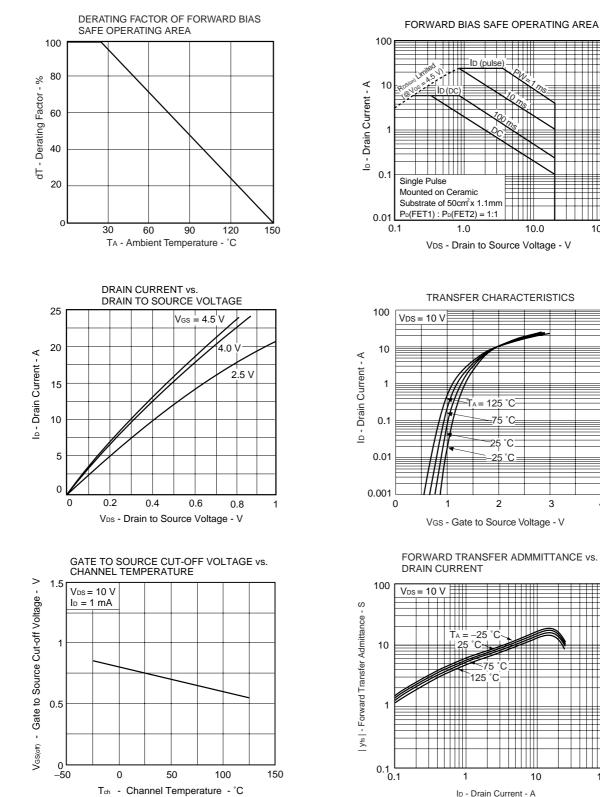


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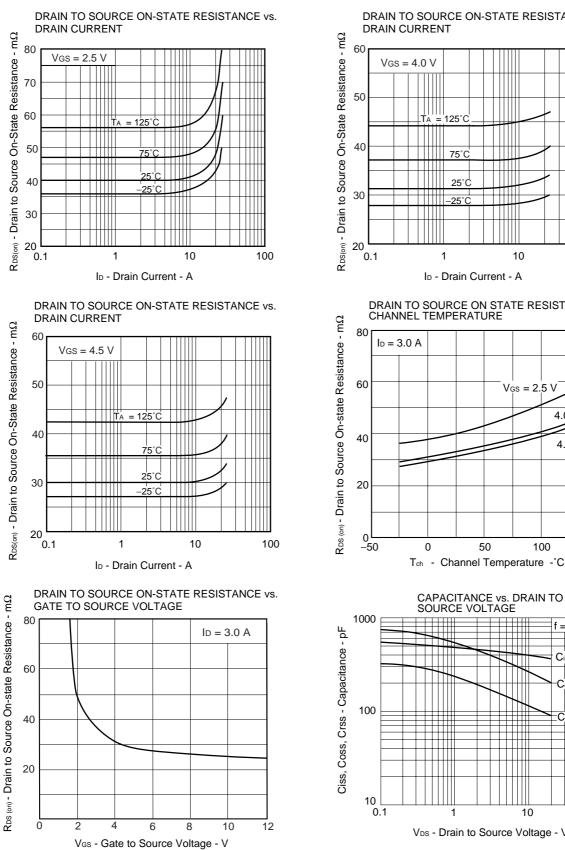
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TYPICAL CHARACTERISTICS ($T_A = 25^{\circ}C$)

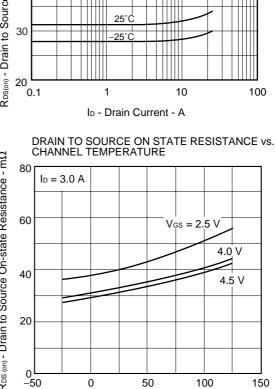
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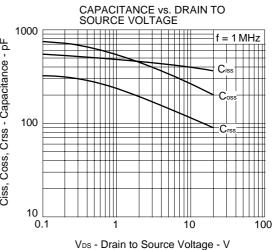


DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

125°C

75°C

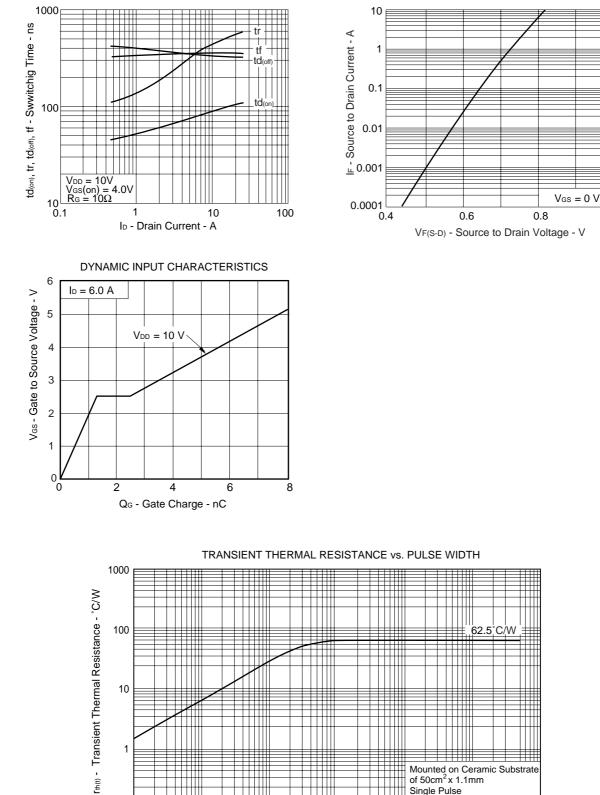




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Data Sheet D12803EJ1V0DS00

1



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SWITCHING CHARACTERISTICS

SOURCE TO DRAIN DIODE FORWARD VOLTAGE

Data Sheet D12803EJ1V0DS00

1

PW - Pulse Width - S

100m

0.1

1m

10m

Mounted on Ceramic Substrate of 50cm² x 1.1mm

1000

PD(FET1) : PD(FET2) = 1:1

100

Single Pulse

10

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